



Photocathode Research @ Cornell

Jared Maxson

On behalf of

Luca Cultrera, Ivan Bazarov, and the entire Cornell
photoemission team

IPAC 2019



**Photocathodes
for high
brightness
applications**

**Long Lifetime
Polarized
photocathodes**

**Photocathodes
for
photodetector
applications**



Photocathodes for high brightness applications

Exploring a wide array of materials:

- Full family of alkali antimonides
- CsTe
- GaAs and GaN
- Quantum materials (like topological insulators)
- Ever growing...

We think broadly about high brightness applications:

- ERL @ Cornell: *Cbeta* (*See posters by C. Gulliford*)
- Femtosecond electron diffraction, microscopy and spectrosocpy
- XFEL light sources

The “master equation” :

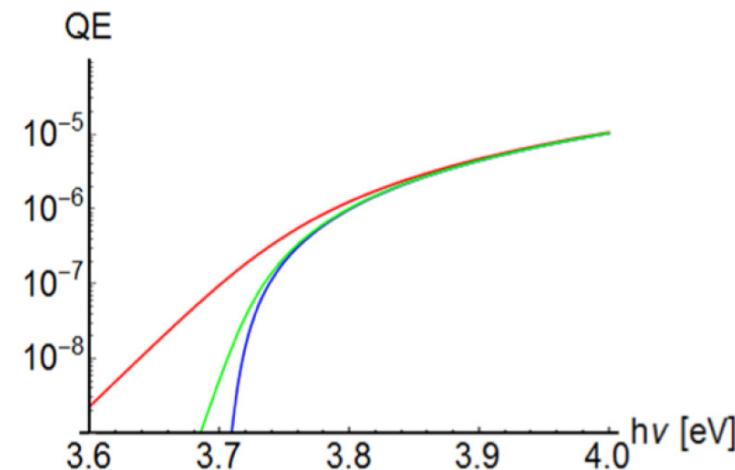
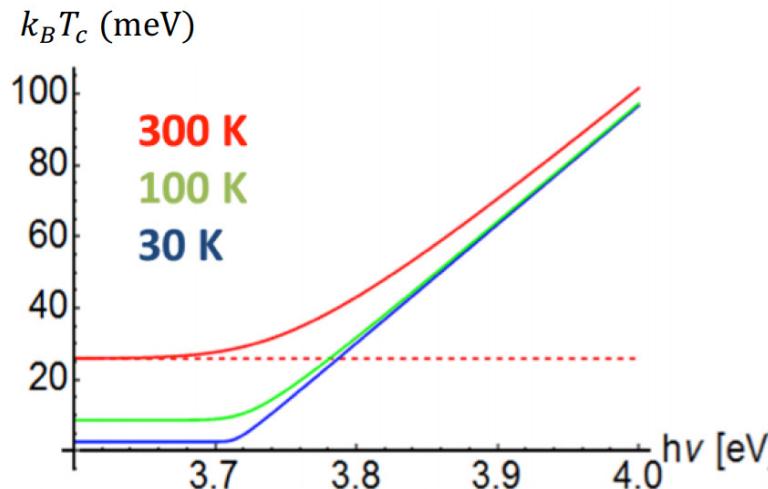
$$B_{max} = B_{source} \propto \frac{E_{cath}^n}{kT_e}$$

$n \geq 1$
(depends on specifics)

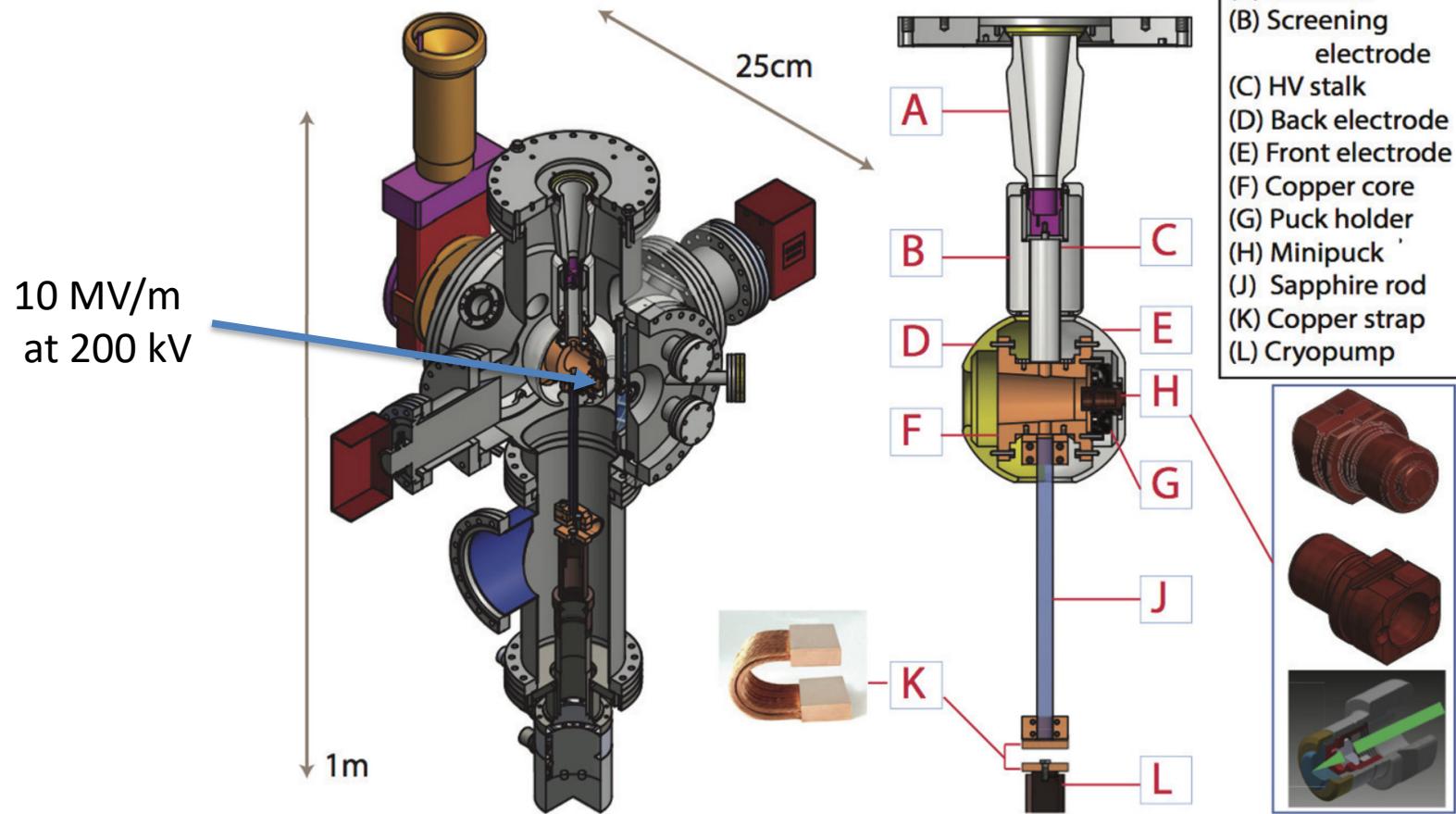
Effective beam temperature
at the source



- For a free electron metal, where $E = \frac{(\hbar k)^2}{2m_e}$, here Cu:



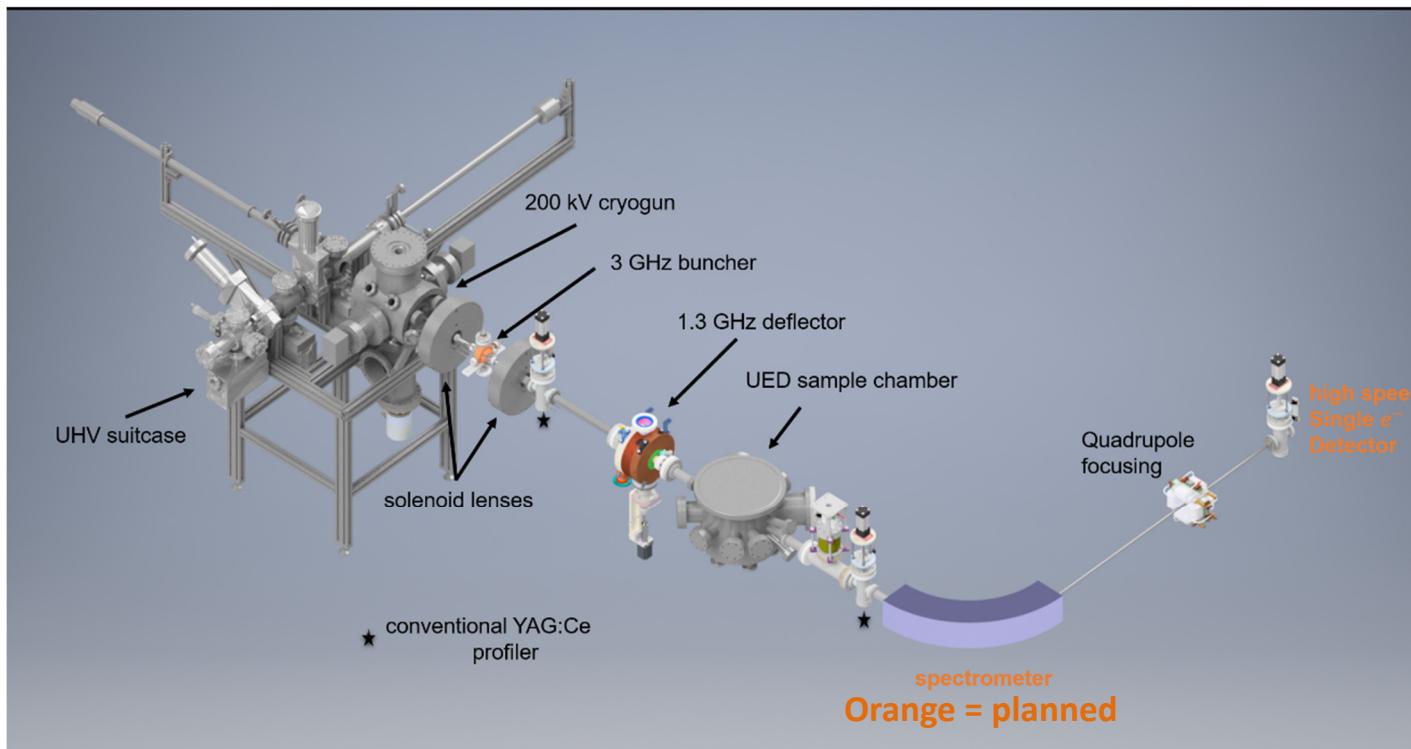
- Big potential gains for low T operation.** 30 K $\rightarrow \sim 3$ meV, $>30\times$ less than typical Cu in RF photoinjectors.
- Penalty: you're emitting from the Fermi tail—not many electrons there!
- S. Karkare et al: extreme low kT_e (6 meV) result from cold Cu (publication forthcoming).



Cathode Cooled to ~40 K. Inverted insulator design *a la* Jlab.



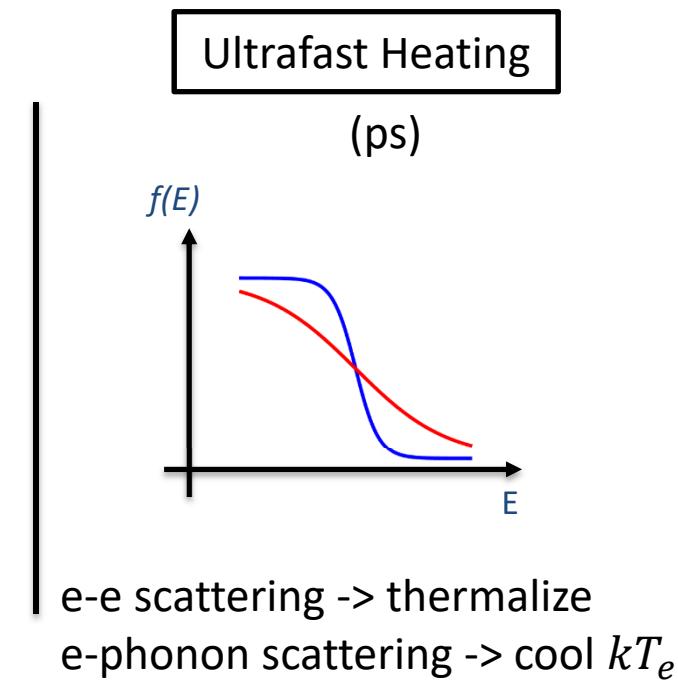
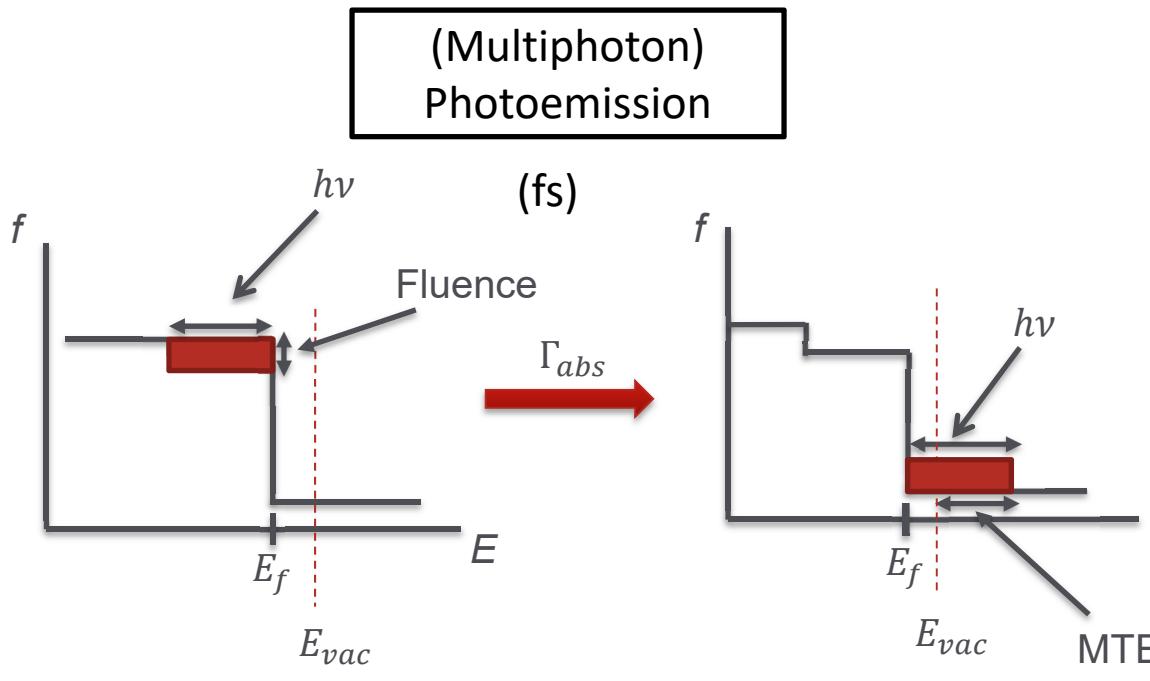
- What will the cold gun do? A new UED and photoemission physics beamline
 - Physics of high brightness beams at small spatial (< nm) and temporal scales (100 fs and below).



- Short pulses and low QE? The beamline will hence also study photoemission physics at *high laser intensity*.

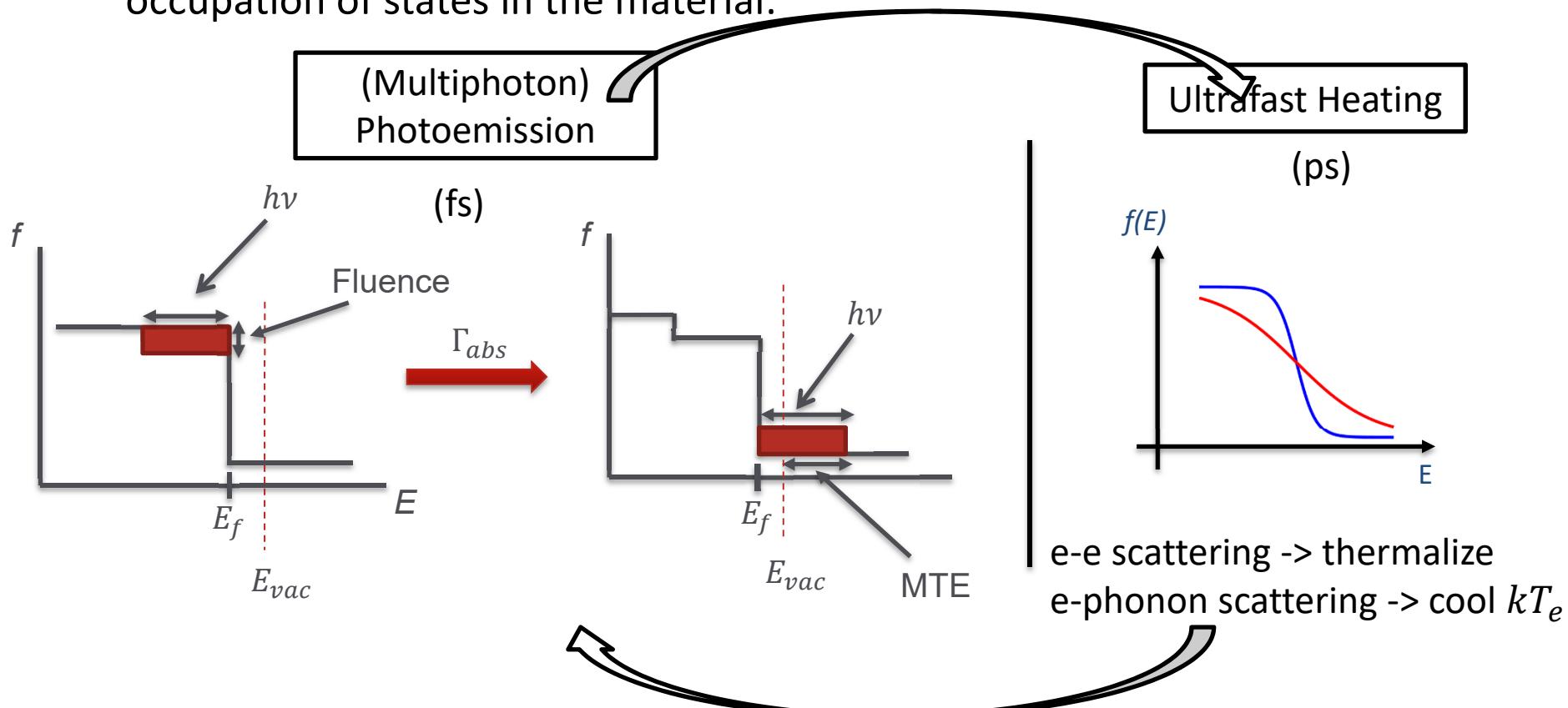


- Low QE necessitates the use of high fluence lasers.
- At high fluences (mJ/cm^2), the idea of “equilibrium photoemission” breaks down.
- Must think about photoemission as dynamic: the laser modifies the occupation of states in the material:



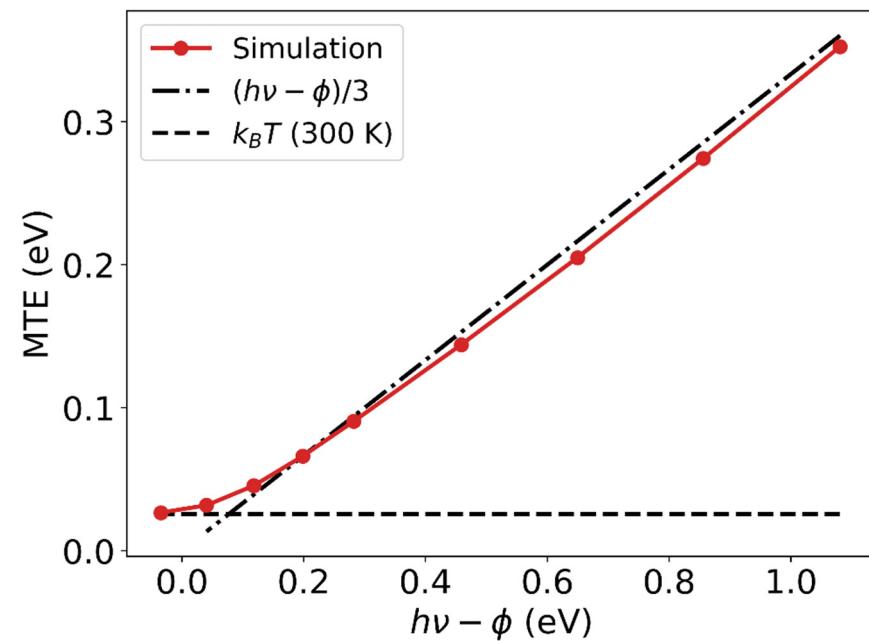
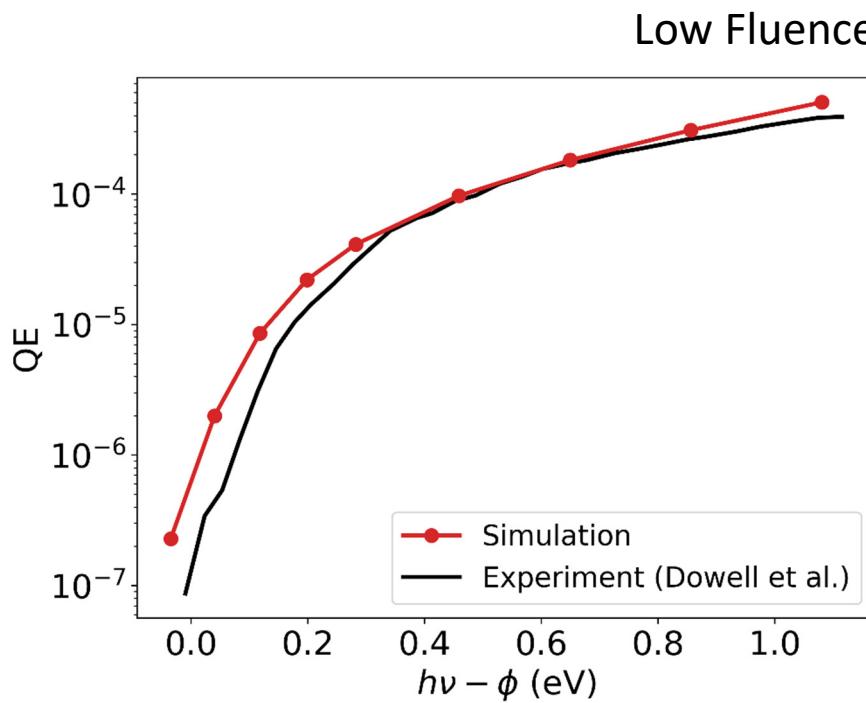


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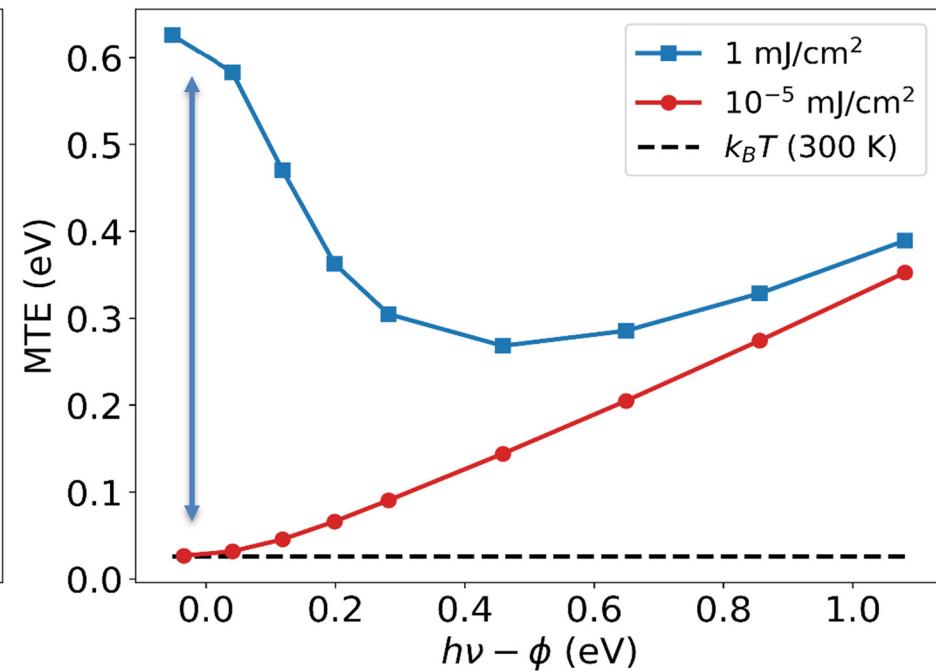
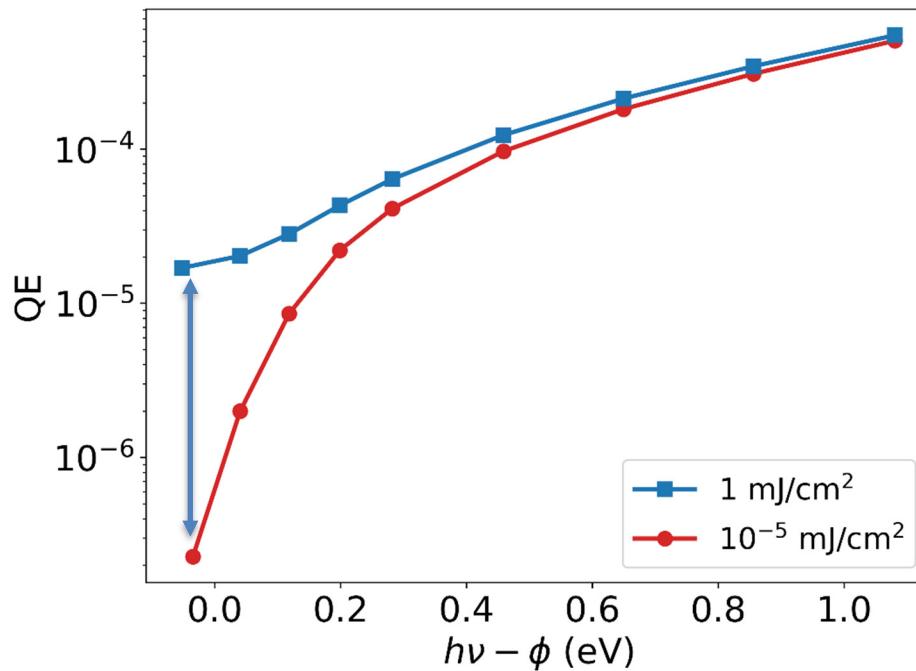


- Recalculate QE and kT_e from first principles with a changing $f(E)$ using Boltzmann equation approach.
- For a 50 fs laser pulse and a Cu cathode:



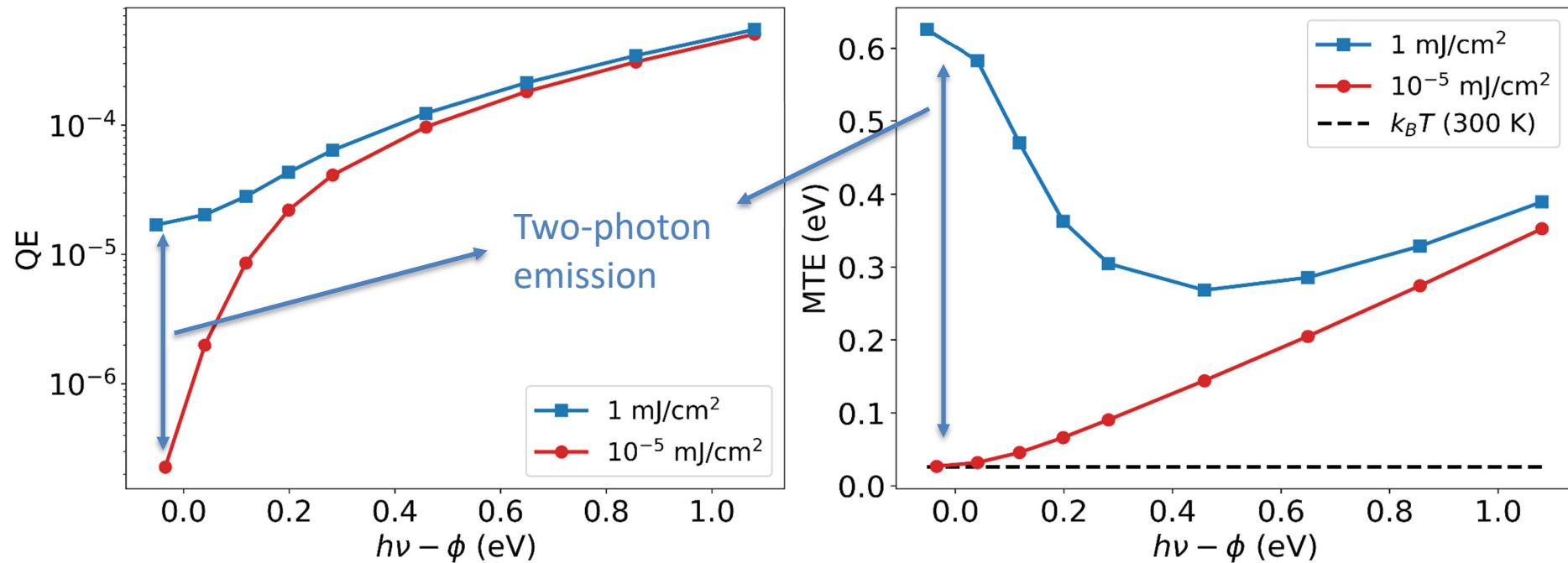


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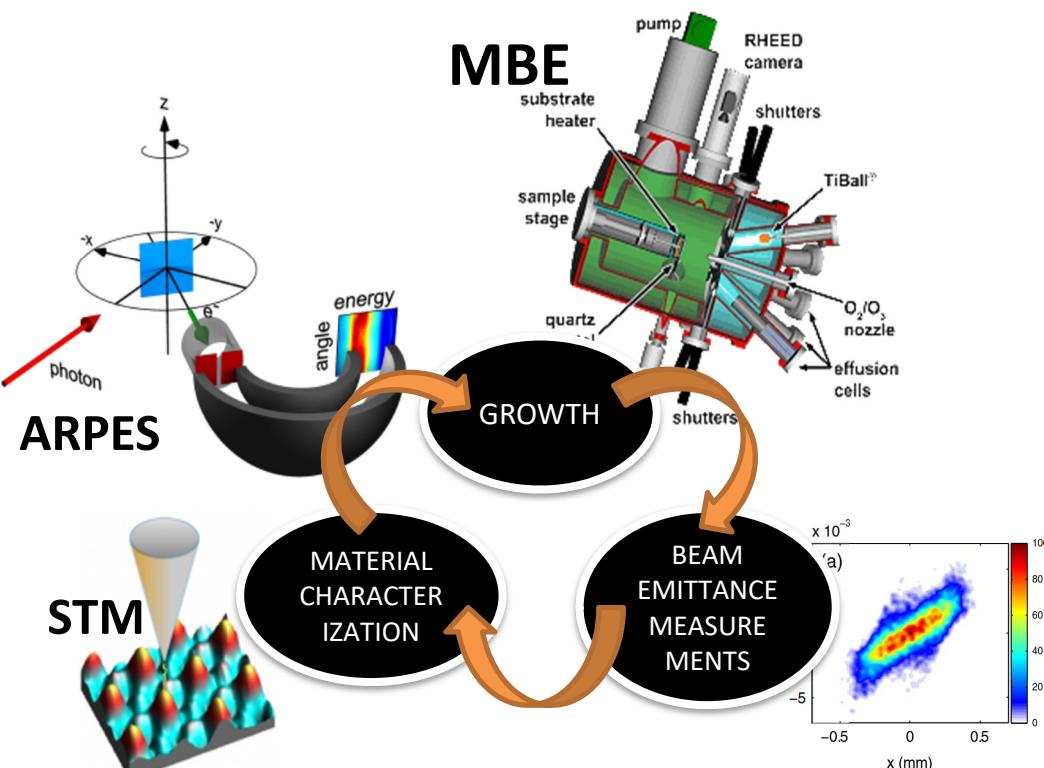
Brightness in the equilibrium regime

- Recalculate QE and kT_e from first principles with a changing $f(E)$ using Boltzmann equation approach.
- For a 50 fs laser pulse and a Cu cathode:





Explore new photocathode materials...like a material scientist!



- Goals:

- Control of the photocathode physical & chemical properties
- Ordered materials: grown in e.g. MBE, measured in ARPES (band structure), STM (surface properties), XPS (composition)...

- Solution:

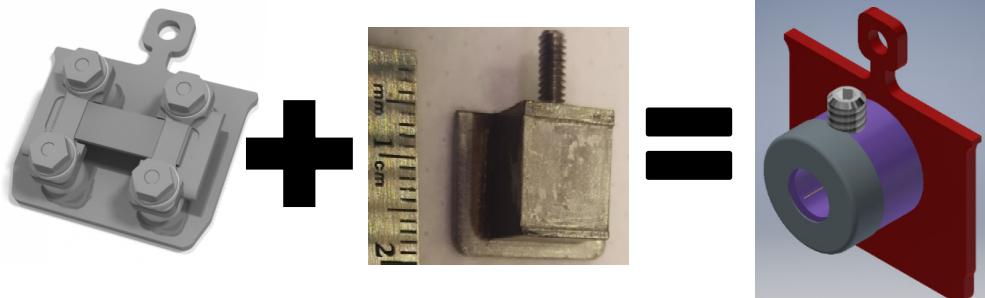
- Universal sample holder and manipulation system **integrated with a high field cryocooled DC gun**.
- UHV transfer with vacuum suitcase



Cryogenic TE meter: dedicated beam emittance measurement system

NEW INSTRUMENT

- 1 meV resolution
- Cryogenic (down to LHe)
- Realistic operating condition
 - Gradient similar to injector (>10 MV/m)
 - SRF injector operating T
- Compatible with sample holders:

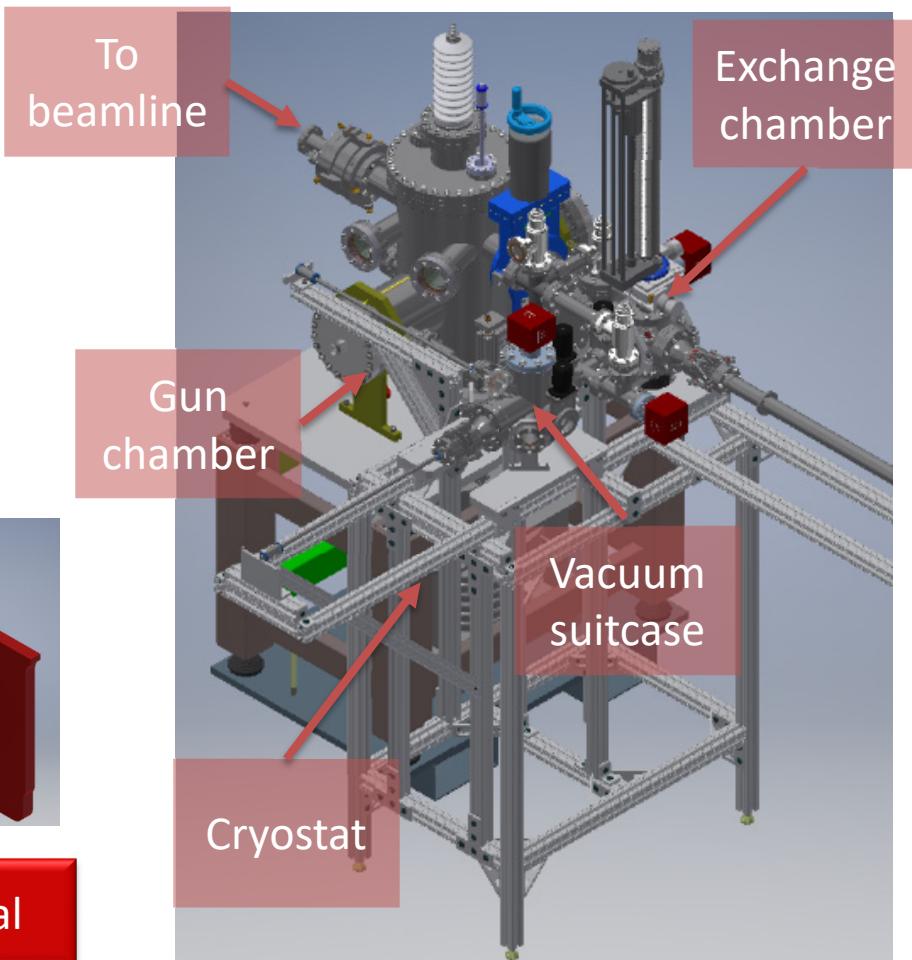


Standard
Omicron

MBE/ARPES

Universal

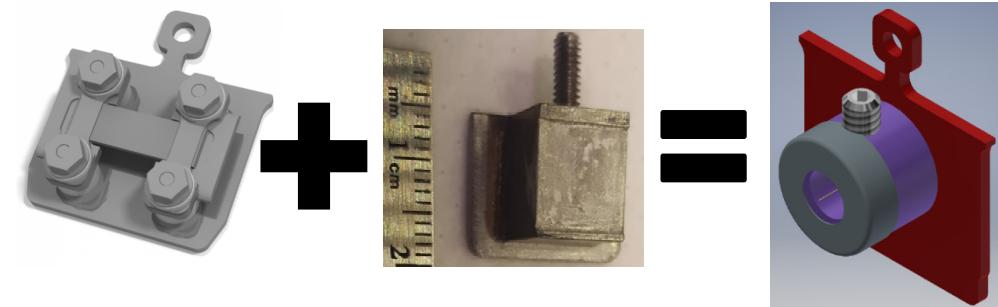
TE meter with exchange chamber
and vacuum suitcase





NEW INSTRUMENT under construction

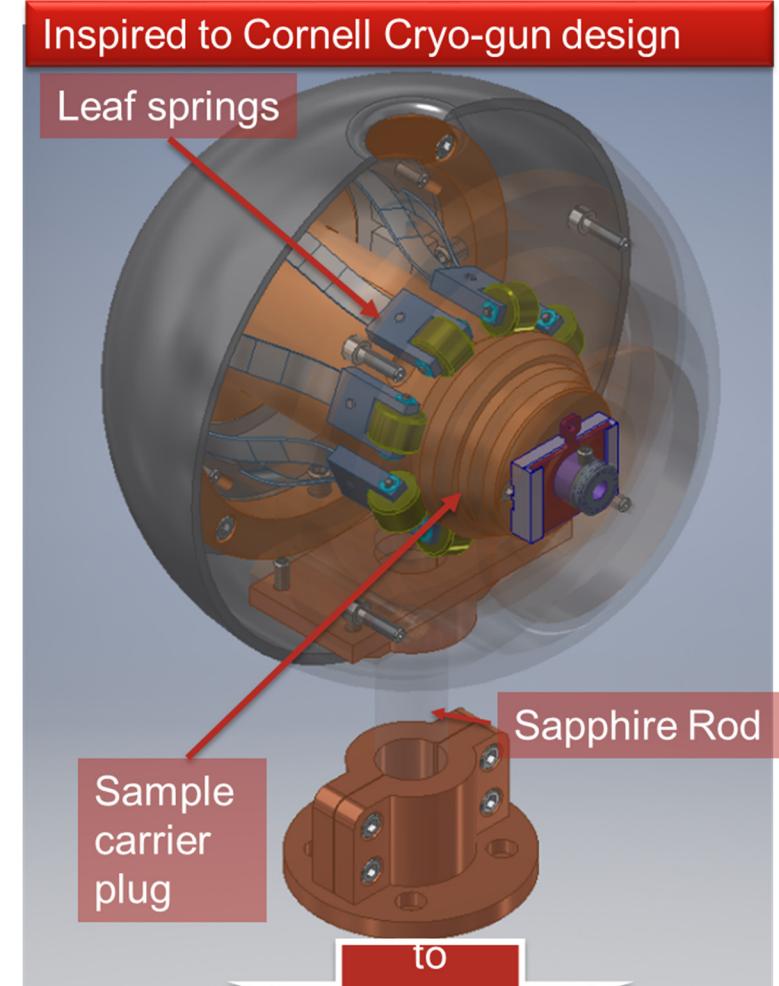
- 1 meV transverse energy resolution
- Cryogenic (down to LHe)
- Realistic operating condition
 - Gradient similar to injector (>10 MV/m)
 - SRF injector operating T
- Compatible with sample holders:

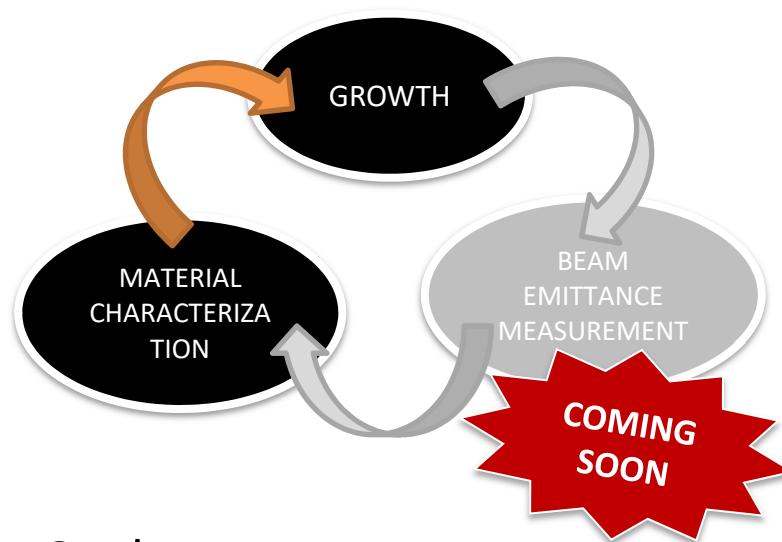


Standard
Omicron

MBE/ARPES

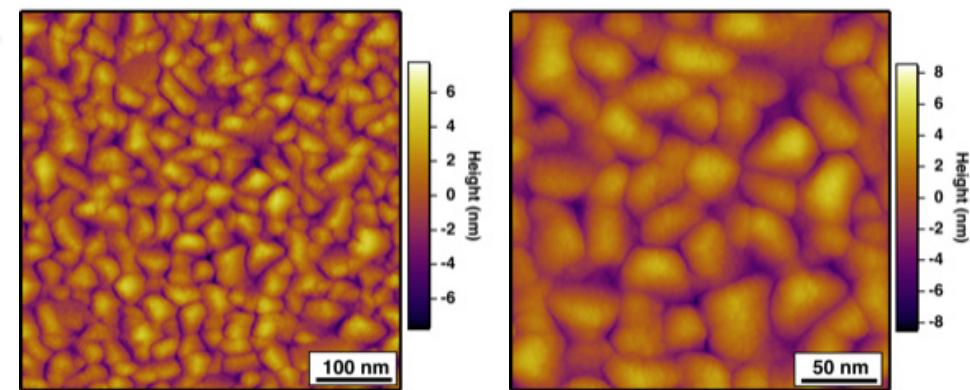
Universal





- Goals:
 - minimize the roughness of Cs₃Sb samples to reduce intrinsic emittance
 - Ensure chemical homogeneity of the samples (Cs¹⁺, Sb³⁻, Cs⁰, Sb⁵⁺...)
 - Study the influence of substrate materials on the samples' morphology

Transfer to Surface Science laboratory via vacuum suitcase



STM images of Cs₃Sb samples grown on H-terminated Si

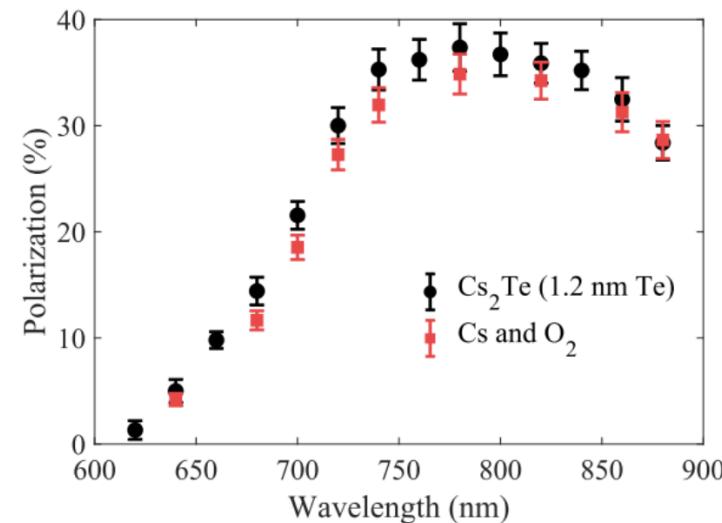
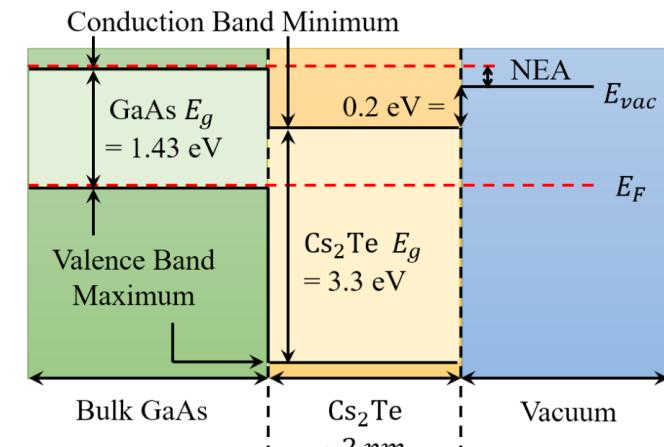
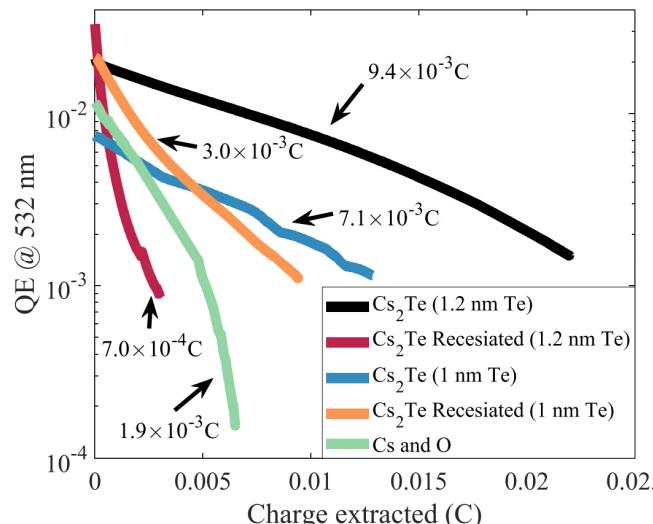


Long Lifetime Polarized photocathodes

- Emittance is not the only figure of merit for photocathodes...
- Nuclear physics and HEP machines of the future may need **high polarization and long lifetime**
- Cesium GaAs remains the state of the art in high QE polarized photocathodes.
- Charge lifetime is still a challenging issue!

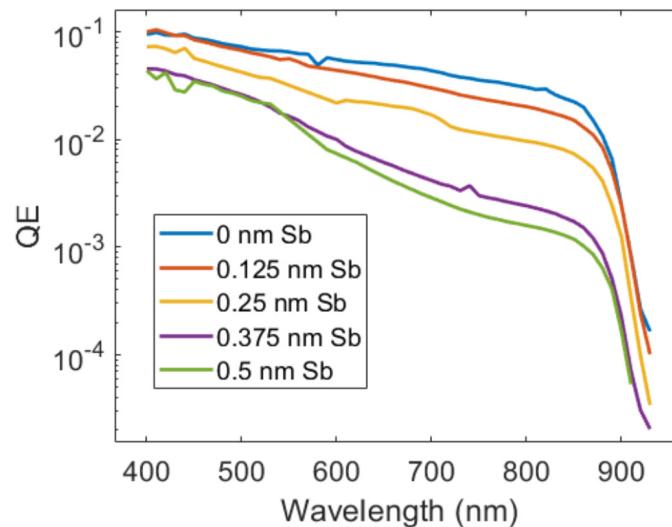


- Recently, GaAs coated with Cs_2Te has shown to yield negative electron affinity activation. Cs_2Te is also known to be a robust photocathode! Does a protective coating harm the polarization?
- For a ~ 2 nm layer—the answer is no!
- Does it actually protect? 5x longer charge lifetime as compared to activation with just Cs and O.



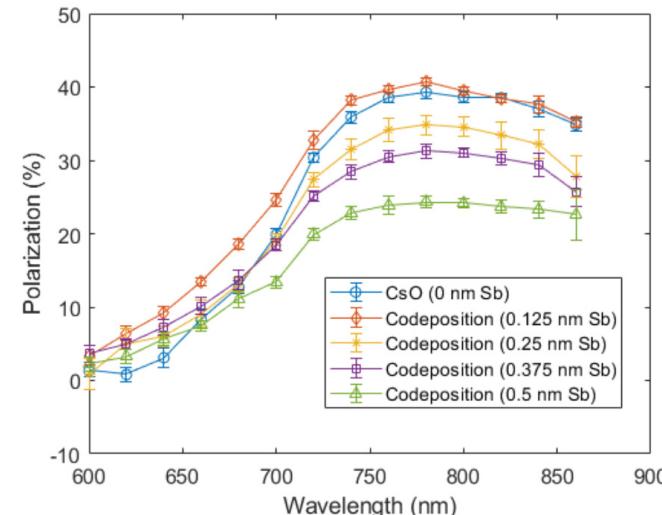
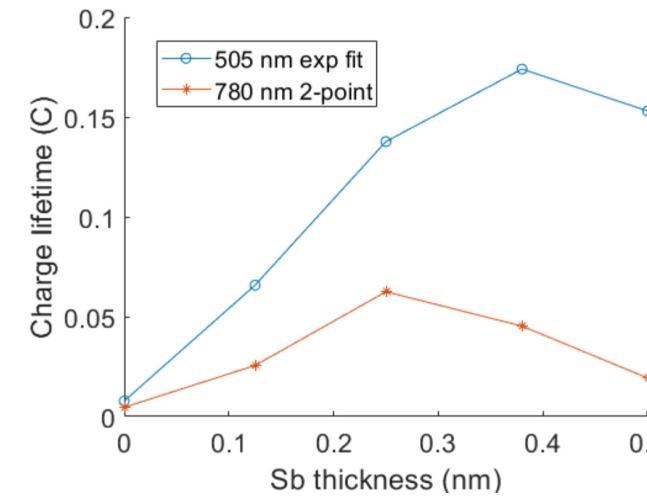


- **Exciting new result : GaAs NEA activation with Cs_3Sb !**



Lifetime improved beyond
that achieved with CsTe coating,
with high QE in the IR!

Tradeoff between thickness, lifetime
And polarization—studies are ongoing.



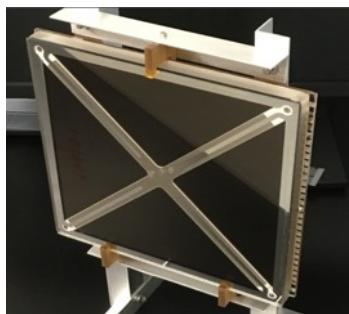


Photocathodes for photodetector applications

- “And now for something completely different!”
- We have spent years studying the growth and optimization of alkali antimonide photocathodes...
- Beyond just accelerators, there are other HEP relevant applications of high QE photocathodes:
photodetectors.

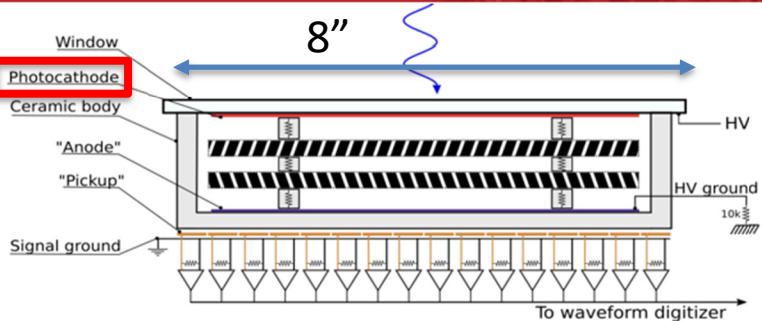


Photocathode for LAPPD™



Incom LAPPD™

UHV growth chamber based on effusion cell filled with elemental materials is part of CU photocathode lab.



- Transmission mode high peak QE;
- 0.5 π Uniformity over large area;
- Infrared response (bonus);
- Scalable for mass production;

1- All UHV process (Growth and UHV seal)



From R&D
to mass
production

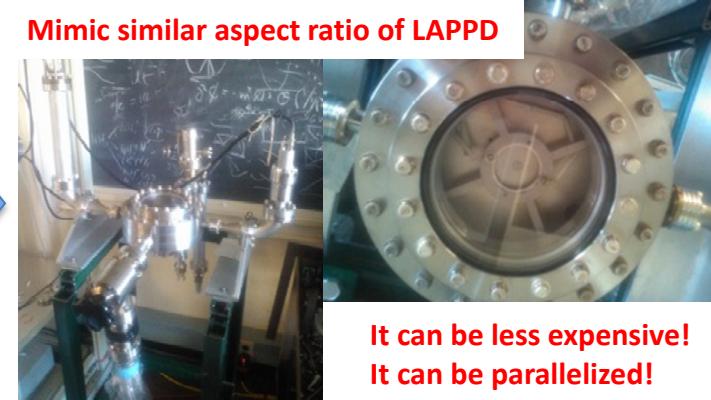


24,000 6-inch wafers per year

2- In situ process (Only final reaction with alkali in UHV sealed device)



From mass
production
to R&D



Mimic similar aspect ratio of LAPPD

It can be less expensive!
It can be parallelized!



1.5" Transmission-mode photocathodes

All UHV process

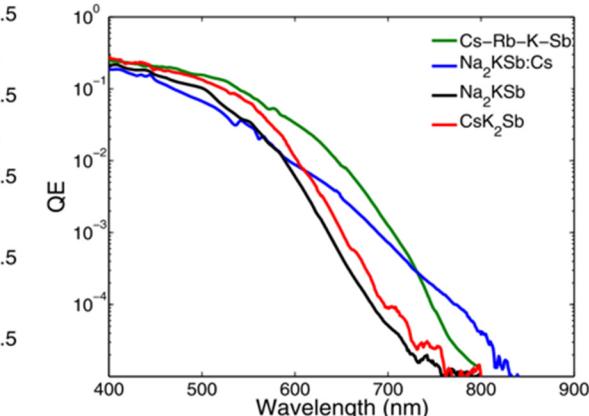
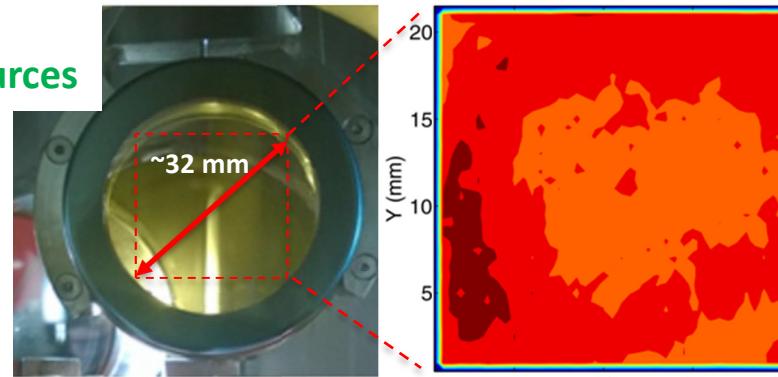
MBE-like elemental sources

Transmission mode!

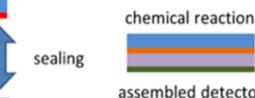
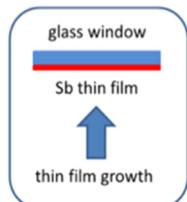
Uniform QE!

High peak QE!

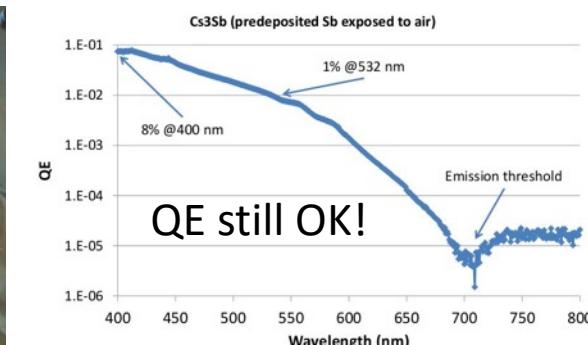
Infrared response!



PMT-like process

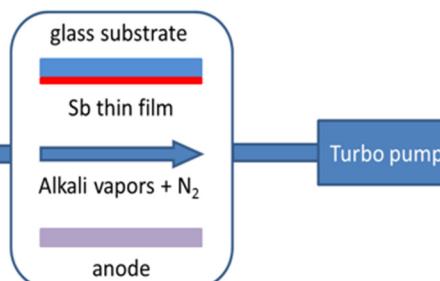


Involves air exposure of the Sb to open air to perform the seal of the tile



Thermal decomposition of CsN₃

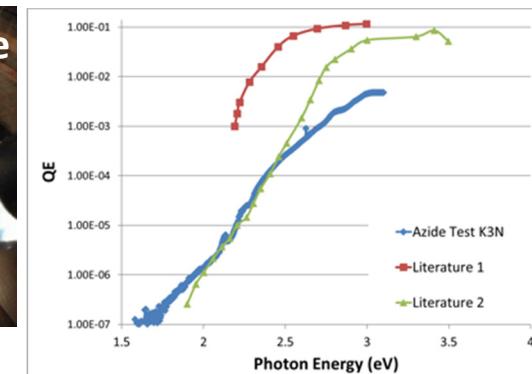
Alkali azides



Cs is highly volatile and Cs₃Sb has already high QE



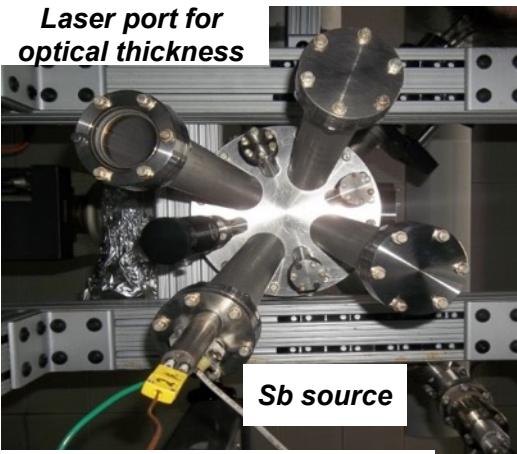
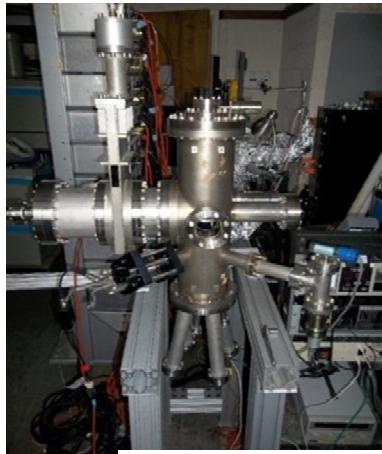
High purity CsN₃ is discontinued worldwide and we used KN₃ instead.



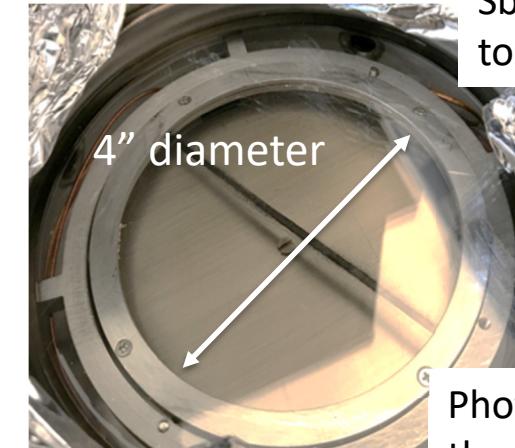


4" Transmission-mode photocathodes

New unique setup where we can study the growth process in a non line of sight conditions like the one imposed by the geometrical constraint of LAPPD™ like detectors.



1st step: grow an Sb film onto a optically transparent substrate using effusion cells (quartz microbalance and optical thickness used as guide)

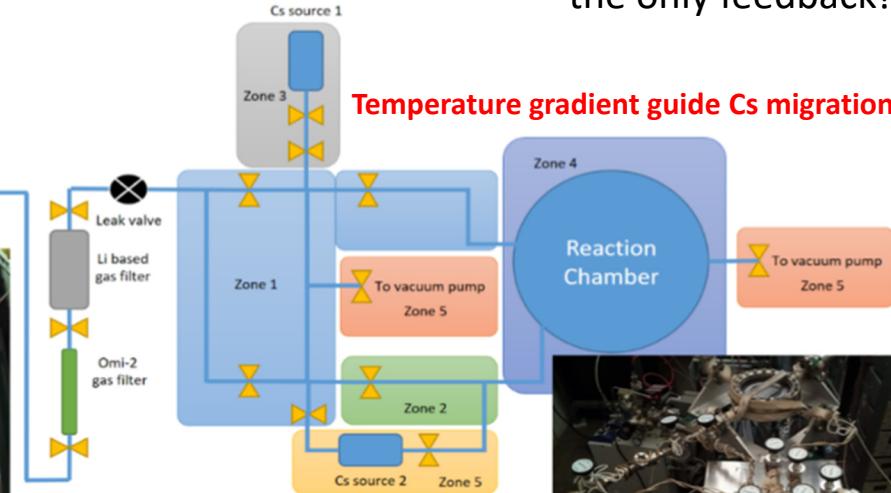
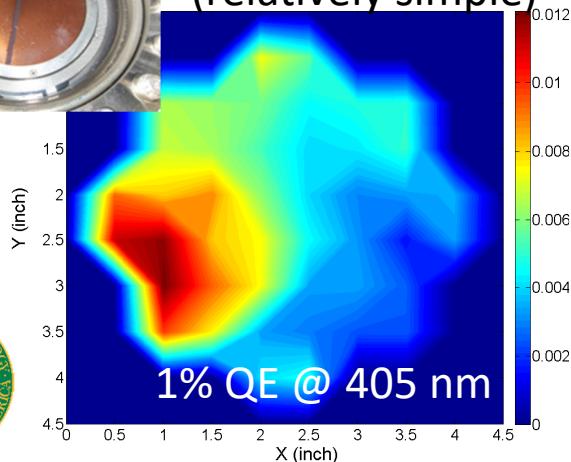


Sb thickness used to optimize QE

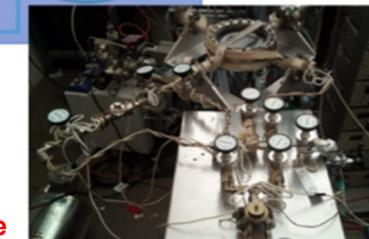
Photocurrent still is the only feedback!



Cesium antimonide
(relatively simple)



2nd step: air transfer the Sb coated glass into the reaction chamber and expose it to alkali metal vapors in a non-line-of-sight geometrical configuration.





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Acknowledgements

- The whole photocathode team: I. Bazarov, L. Cultrera, A. Galdi, J. Bae, C. Duncan, W. Li, C. Pierce, F. Ikponmwen, T. Moore, M. Hines, W. DeBenedetti, J. Balajka
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